# **Six-Output PTIC Control IC**

#### Introduction

TCC-206 is a six-output high-voltage digital to analog control IC specifically designed to control and bias ON Semiconductor's Passive Tunable Integrated Circuits (PTICs).

These tunable capacitor control circuits are intended for use in mobile phones and dedicated RF tuning applications. The implementation of ON Semiconductor's tunable circuits in mobile phones enables significant improvement in terms of antenna radiated performance.

The tunable capacitors are controlled through a bias voltage ranging from 1 V to 24 V. The TCC-206 high-voltage PTIC control IC has been specifically designed to cover this need, providing six independent high-voltage outputs that control up to six different tunable PTICs in parallel. The device is fully controlled through a multi-protocol digital interface.

#### **Key Features**

- Controls ON Semiconductor's PTIC Tunable Capacitors
- Compliant with Timing Needs of Cellular and Other Wireless System Requirements
- Integrated Boost Converter with 6 Programmable DAC Outputs (up to 24 V)
- Low Power Consumption
- Auto-detection of SPI (30- or 32-bit) or MIPI RFFE Interfaces (1.8 V)
- Available in WLCSP (RDL ball arrays)
- Compliant with MIPI 26 MHz Read-Back
- This is a Pb-Free Device

#### **Typical Applications**

• Multi-band, Multi-standard, Advanced and Simple Mobile Phones

1

- Tunable Antenna Matching Networks
- Compatible with Closed-loop and Open-loop Antenna Tuner Applications



#### ON Semiconductor®

www.onsemi.com



WLCSP4 CASE 567JV

#### **MARKING DIAGRAM**



= Assembly Location

= Wafer Lot

= Year

W = Work Week

■ = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 31 of this data sheet.

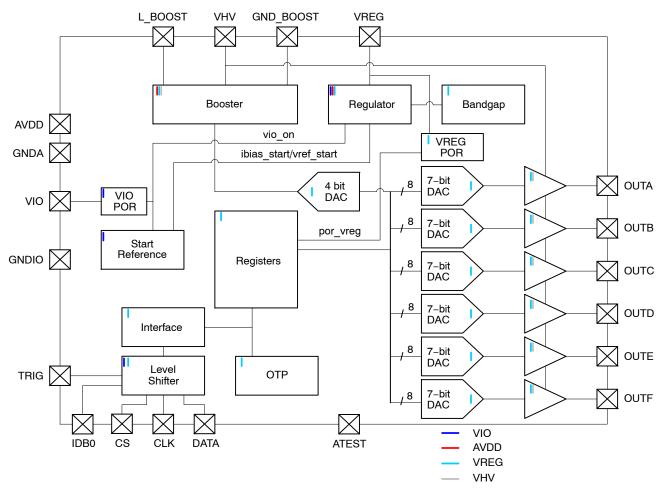


Figure 1. Control IC Functional Block Diagram

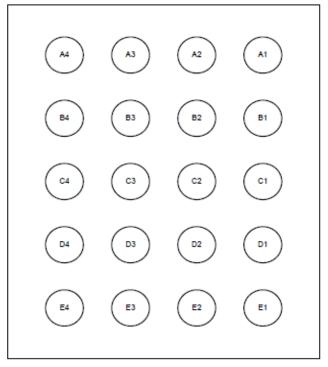


Figure 2. Die Bump Side View

#### **RDL PIN OUT**

**Table 1. PAD DESCRIPTIONS** 

RDL	Name	Туре	Description
A1	OUTF	AOH	High Voltage Output F
A2	VREG	AO	Regulator Output
А3	GND_BOOST	Р	Ground for Booster
A4	VHV	AOH / AIH	Boost High Voltage can be Forced Externally
B1	OUTE	AOH	High Voltage Output E
B2	ATEST	AO	Analog Test Out (Note 1)
B3	AVDD	Р	Analog Supply
B4	L_BOOST	AOH	Boost Inductor
C1	OUTD	AOH	High Voltage Output D
C2	IDB0	DI	MIPI RFFE ID Bit 0 (Note 2)
C3	GNDA	Р	Analog Ground
C4	TRIG	DIO	Trigger Signal Input (Note 3)
D1	OUTC	АОН	High Voltage Output C
D2	GNDIO	Р	Digital IO Ground
D3	CS	DI	Chip Select for SPI
D4	CLK	DI	MIPI RFFE / SPI Clock
E1	OUTB	AOH	High Voltage Output B
E2	OUTA	AOH	High Voltage Output A
E3	VIO	Р	Digital IO Supply
E4	DATA	DIO	Digital IO (SPI and MIPI RFFE)

- To be grounded when not in use.
   This pin has to be connected to either GNDIO or VIO level, even if only SPI protocol is used. Never let it float.
- 3. To be grounded in normal operation.

#### Legend: Pad Types

AIH = High Voltage Analog Input

AO = Analog Output AOH = High Voltage Analog Output

DI = Digital Input

DIO = Digital Input/Output (IO)

P = Power

#### **ELECTRICAL PERFORMANCE SPECIFICATIONS**

**Table 2. ABSOLUTE MAXIMUM RATINGS** 

Symbol	Parameter	Rating	Unit
AVDD	Analog Supply Voltage	-0.3 to +6.0	V
VIO	IO Reference Supply Voltage	-0.3 to +2.5	V
V <sub>I/O</sub>	Input Voltage Logic Lines (DATA, CLK, CS)	-0.3 to V <sub>IO</sub> + 0.3	V
V <sub>(sub)HVH</sub>	VHV Maximum Voltage	-0.3 to 30	V
V <sub>ESD (HBM)</sub>	Human Body Model, JESD22-A114, All I/O	2,000	V
V <sub>ESD (MM)</sub>	Machine Model, JESD22-A115	200	V
T <sub>STG</sub>	Storage Temperature	-55 to +150	°C
T <sub>AMB_OP_MAX</sub>	Max Operating Ambient Temperature without Damage	+110	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Table 3. RECOMENDED OPERATING CONDITIONS** 

Symbol	Parameter	Min	Тур	Max	Unit
T <sub>AMB_OP</sub>	Operating Ambient Temperature	-30	-	+85	°C
$T_{J\!=\!OP}$	Operating Junction Temperature	-30	-	+125	°C
AVDD	Analog Supply Voltage	2.3	-	5.5	V
VIO	IO Reference Supply Voltage	1.62	=	1.98	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

**Table 4. DC CHARACTERISTICS** ( $T_A$  = -30 to  $+85^{\circ}$ C;  $V_{OUTX}$  = 15 V for each output; 2.3 V<AVDD< 5.5 V;  $V_{IO}$  = 1.8 V;  $R_{LOAD}$  = equivalent series load of 5.6 kΩ and 2.7 nF;  $C_{HV}$  = 22 nF;  $L_{BOOST}$  = 15  $\mu$ H; TRIG pin grounded; unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Unit	Comment
SHUTDOWN M	ODE	l.	l .	· I		
I <sub>AVDD</sub>	AVDD Supply Current	-	-	1.5	μА	VIO Supply is Low
I <sub>L_BOOST</sub>	L_BOOST Leakage	-	-	1.5		
I <sub>BATT</sub>	Battery Current	-	-	2.5		
I <sub>VIO</sub>	VIO Supply Current	-1	-	1		
I <sub>CLK</sub>	CLK Leakage	-1	-	1		
I <sub>DATA</sub>	DATA Leakage	-1	-	1		
ACTIVE MODE						
I <sub>BATT</sub>	Average battery current, 3 outputs actively switching 16 V for 1205 μs to 2 V for 1705 μs to 8 V for 1705 μs and 3 outputs are @ 16 V steady state	_	1,760	2,350	μΑ	At VHV = 20 V AVDD = 3.3 V
I <sub>BATT_</sub> SS0	Average battery current, 6 outputs @ 0 V steady state	-	800	1,130		At VHV = 20 V AVDD = 3.3 V
I <sub>BAT_SS2</sub>	Average battery current, 6 outputs @ 2 V steady state	-	850	1,200	μΑ	At VHV = 20 V AVDD = 3.3 V
I <sub>BATT_</sub> SS16	Average battery current, 6 outputs @ 16 V steady state	-	1,190	1,560		At VHV = 20 V AVDD = 3.3 V
I <sub>L_BOOST</sub>	Average inductor current, 3 outputs actively switching 16 V for 1205 μs to 2 V for 1705 μs to 8 V for 1705 μs and 3 outputs are @ 16 V steady state	-	1,480	2,050		At VHV = 20 V AVDD = 3.3 V
I <sub>L_BOOST_SS0</sub>	Average inductor current, 6 outputs @ 0 V steady state	_	500	790		At VHV = 20 V AVDD = 3.3 V
I <sub>L_BOOST_SS2</sub>	Average inductor current, 6 outputs @ 2 V steady state	_	560	850		At VHV = 20 V AVDD = 3.3 V
I <sub>L_BOOST_SS16</sub>	Average inductor current, 6 outputs @ 16 V steady state	-	930	1,270		At VHV = 20 V AVDD = 3.3 V
I <sub>VIO_INACT</sub>	VIO average inactive current	-	-	3	1	VIO is high, no bus activity
I <sub>VIO_</sub> ACTIVE	VIO average active current	-	-	250		VIO = 1.8 V, master sending data at 26 MHz
$V_{VREG}$		1.7	-	1.9	V	No external load allowed

**Table 4. DC CHARACTERISTICS** ( $T_A$  = -30 to  $+85^{\circ}$ C;  $V_{OUTX}$  = 15 V for each output; 2.3 V<AVDD< 5.5 V;  $V_{IO}$  = 1.8 V;  $R_{LOAD}$  = equivalent series load of 5.6 kΩ and 2.7 nF;  $C_{HV}$  = 22 nF;  $L_{BOOST}$  = 15  $\mu$ H; TRIG pin grounded; unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Unit	Comment
LOW POWER N	ODE					
I <sub>AVDD</sub>	AVDD Supply Current	_	-	8	μΑ	
I <sub>L_BOOST</sub>	L_BOOST Leakage	_	-	6		
I <sub>BATT</sub>	Battery Current	_	-	14		I <sub>AVDD</sub> + I <sub>L_BOOST</sub>
I <sub>VIO</sub>	VIO Supply Current	_	-	3		No bus activity
$V_{VREG}$		1.6	-	1.9	V	No external load allowed

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **Table 5. BOOST CONVERTER CHARACTERISTICS**

(AVDD from 2.3 V to 5.5 V;  $V_{IO}$  = 1.8 V;  $T_A$  = -30 to +85°C;  $C_{HV}$  = 22 nF;  $L_{BOOST}$  = 15  $\mu$ H; unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VHV_min	Minimum programmable output volt- age (average), DAC Boost = 0h	Active mode	-	13	-	V
VHV_max	Maximum programmable output voltage (average), DAC Boost = Fh	Active mode	-	28	-	
Resolution	Boost voltage resolution	4-bit DAC	-	1	-	
I <sub>L_BOOST_LIMIT</sub>	Inductor current limit		_	200	-	mA

Table 6. ANALOG OUTPUTS (OUT A, OUT B, OUT C, OUT D, OUT E, OUT F) (AVDD from 2.3 V to 5.5 V;  $V_{IO}$  = 1.8 V;  $V_{HV}$  = 26 V;  $T_A$  = -30 to +85°C;  $R_{load}$  =  $\infty$  unless otherwise specified)

Parameter	Description	Min	Тур	Max	Unit	Comment
SHUTDOWN	MODE					
Z <sub>OUT</sub>	OUT A, OUT B, OUT C , OUT D, OUT E,OUT F output impedance	7	_	_	МΩ	DAC disabled
ACTIVE MOD	DE					
V <sub>OH</sub>	Maximum output voltage	_	23.8	-	V	DAC A, B, C, D, E or F = 7Fh, DAC Boost = Fh, $I_{OH}$ < 10 $\mu$ A
V <sub>OL</sub>	Minimum output voltage	_	_	1	V	DAC A, B C, D, E or F = 01h, DAC Boost = 0h to Fh, I <sub>OH</sub> < 10 µA
Slew Rate		-	3	10	μs	2 V to 20 V step, measured at $V_{OUT}$ = 15.2 V, $R_{LOAD}$ = equivalent series load of 2.7 kΩ and 5.6 nF, Turbo enabled
R <sub>PD</sub>	OUT A, OUT B, OUT C, OUT D, OUT E, OUT F set in pull-down mode	-	-	1000	Ω	DAC A, B C, D, E or F = 00h, DAC Boost = 0h to Fh, selected output(s) is disabled
Resolution	Voltage resolution (1-bit)	-	188	_	mV	(1 LSB = 1-bit)
V <sub>OFFSET</sub>	Zero scale, least squared best fit	-1	-	+1	LSB	
Error		-3.0	-	+3.0	%V <sub>OUT</sub>	Over 2 V – 20 V V <sub>O</sub> range
DNL	Differential non-linearity least squared best fit	-0.9	-	+0.9	LSB	Over 2 V – 20 V V <sub>O</sub> range
INL	Integral non-linearity least squared best fit	-1	_	+1	LSB	Over 2 V – 20 V V <sub>O</sub> range
I <sub>SC</sub>	Over current protection	-	5	65	mA	Any DAC output shorted to ground
V <sub>RIPPLE</sub>	Output ripple with all outputs at steady state	_	_	40	mV RMS	Over 2 V – 20 V for VHV = 23.5 V

#### THEORY OF OPERATION

#### Overview

The control IC outputs are directly controlled by programming the six DACs (DAC A, DAC B, DAC C, DAC D, DAC E and DAC F) through the digital interface.

The DAC stages are driven from a reference voltage, generating an analog output voltage driving a high-voltage amplifier supplied from the boost converter (see Figure 1 – Control IC Functional Block Diagram).

The control IC output voltages are scaled from 0 V to 24 V, with 128 steps of 188 mV ( $(2 \times 24 / 255 \text{ V}) = 0.188235 \text{ V}$ ). The nominal control IC output can be approximated to 188 mV x (DAC value).

For performance optimization the boost output voltage (VHV) can be programmed to levels between 13 V and 28 V via the DAC\_boost register (4 bits with 1 V steps). The startup default level for the boosted voltage is VHV = 24 V.

For proper operation and to avoid saturation of the output devices and noise issues it is recommended to operate the boosted VHV voltage at least 2 V above the highest programmed  $V_{\rm OUT}$  voltage of any of the six outputs.

#### **Operating Modes**

The following operating modes are available:

 Shutdown Mode: All circuit blocks are off, the DAC outputs are disabled and placed in high Z state and current consumption is limited to minimal leakage current. The shutdown mode is entered upon initial application of AVDD or upon VIO being placed in the low state. The contents of the registers are not maintained in shutdown mode.

- 2. Startup Mode: Startup is only a transitory mode. Startup mode is entered upon a VIO high state. In startup mode all registers are reset to their default states, the digital interface is functional, the boost converter is activated, outputs OUT A, OUT B, OUT C, OUT D, OUT E and OUT F are disabled and the DAC outputs are placed in a high Z state. Control software can request a full hardware and register reset of the TCC-206 by sending an appropriate PWR\_MODE command to direct the chip from either the active mode or the low power mode to the startup mode. From the startup mode the device automatically proceeds to the active mode.
- 3. Active Mode: All blocks of the TCC-206 are activated and the DAC outputs are fully controlled through the digital interface, DACs remain off until enabled. The DAC settings can be dynamically modified and the HV outputs will be adjusted according to the specified timing diagrams. Each DAC can be individually controlled and/or switched off according to application requirements. Active mode is automatically entered from the startup mode. Active mode can also be entered from the low power mode under control software command.
- 4. Low Power Mode: In low power mode the serial interface stays enabled, the DAC outputs are disabled and are placed in a high Z state and the boost voltage circuit is disabled. Control software can request to enter the low power mode from the active mode by sending an appropriate PWR\_MODE command. The contents of all registers are maintained in the low power mode.

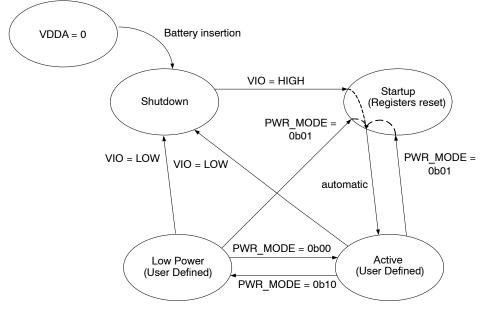


Figure 3. Modes of Operation

#### AVDD Power-On Reset (POR)

Upon application of AVDD the TCC-206 will be in shutdown mode. All circuit blocks are off and the chip draws only minimal leakage current.

#### VIO Power-On Reset and Startup Conditions

A high level on VIO places the chip in startup mode which provides a POR to the TCC-206. POR resets all registers to their default settings as described in Table 8. VIO POR also resets the serial interface circuitry. POR is not a brown-out detector and VIO needs to be brought back to a low level to enable the POR to trigger again.

Table 7. VIO POWER-ON RESET AND STARTUP

Register	Default State for VIO POR	Comment
DAC Boost	[1011]	VHV = 24 V
Power Mode	[01]>[00]	Transitions from shutdown to startup and then automatically to active mode
DAC Enable	[000000]	V <sub>OUT</sub> A, B, C, D, E and F Disabled
DAC A		Output in High-Z Mode
DAC B		Output in High-Z Mode
DAC C		Output in High-Z Mode
DAC D		Output in High-Z Mode
DAC E		Output in High-Z Mode
DAC F		Output in High-Z Mode

#### **VIO Shutdown**

A low level at any time on VIO places the chip in shutdown mode in which all circuit blocks are off. The contents of the registers are not maintained in shutdown mode.

**Table 8. VIO THRESHOLDS** (AVDD from 2.3 V to 5.5 V;  $T_A = -30$  to  $+85^{\circ}$ C unless otherwise specified)

Parameter	Description	Min	Тур	Max	Unit	Comments
VIORST	VIO Low Threshold	-	-	0.2	V	When VIO is lowered below this threshold level the chip is reset and placed into the shutdown state

#### **Power Supply Sequencing**

The AVDD input is typically directly supplied from the battery and thus is the first on. After AVDD is applied and before VIO is applied to the chip, all circuits are in the shutdown state and draw minimum leakage currents. Upon application of VIO, the chip automatically starts up using default settings and is placed in the active state waiting for a command via the serial interface.

**Table 9. TIMING** (AVDD from 2.3 V to 5.5 V;  $V_{IO}$  = 1.8 V;  $T_{A}$  = -30 to  $+85^{\circ}$ C; OUT A, OUT B, OUT C, OUT D, OUT E & OUT F; CHV = 22 nF;  $L_{BOOST}$  = 15  $\mu$ H; VHV = 20 V; Turbo–Charge mode off unless otherwise specified)

Parameter	Description	Min	Тур	Max	Unit	Comments
T <sub>POR_VREG</sub>	Internal bias settling time from shutdown to active mode	_	50	120	μs	For info only
T <sub>BOOST_START</sub>	Time to charge CHV @ 95% of set VHV	_	130	-	μs	For info only
T <sub>SD_TO_ACT</sub>	Startup time from shutdown to active mode	_	180	300	μs	
T <sub>SET+</sub>	Output A, B, C, D, E, F positive settling time to within 5% of the delta voltage, equivalent series load of 5.6 k $\Omega$ and 2.7 nF, $V_{OUT}$ from 2 V to 20 V; 0Bh (11d) to 55h (85d)	-	50	60	μs	Voltage settling time connected on V <sub>OUT</sub> A, B, C, D, E, F
T <sub>SET-</sub>	Output A, B, C, D, E, F negative settling time to within 5% of the delta voltage, equivalent series load of 5.6 k $\Omega$ and 2.7 nF, V <sub>OUT</sub> from 20 V to 2 V; 55h (85d) to 0Bh (11d)	-	50	60	μs	Voltage settling time connected on V <sub>OUT</sub> A, B, C, D, E, F
T <sub>SET+</sub>	Output A, B, C, D, E, F positive settling time with Turbo	-	35	-	μs	Voltage settling time connected on V <sub>OUT</sub> A, B, C, D, E, F
T <sub>SET</sub> -	Output A, B, C, D, E, F negative settling time with Turbo	-	35	-	μs	Voltage settling time connected on V <sub>OUT</sub> A, B, C, D, E, F

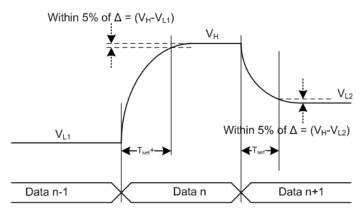


Figure 4. Output Settling Diagram

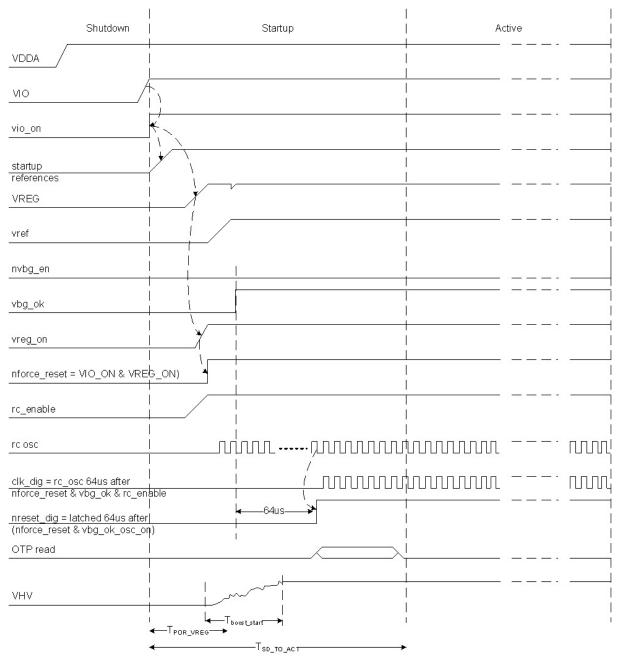


Figure 5. Startup Timing Diagram

#### **Boost Control**

The TCC-206 integrates an asynchronous current control boost converter. It operates in a discontinuous mode and features spread-spectrum circuitry for Electro-Magnetic Interference (EMI) reduction. The average boost clock is 2 MHz and the clock is spread between 0.8 MHz and 4 MHz.

#### **Boost Output Voltage (VHV) Control Principle**

The asynchronous control starts the boost converter as soon as the VHV voltage drops below the reference set by the 4-bit DAC and stops the boost converter when the VHV voltage rises above the reference again.

Due to the slow response time of the control loop, the VHV voltage may drop below the set voltage before the control loop compensates for it. In the same manner, VHV can rise higher than the set value. This effect may reduce the maximum output voltage available. Please refer to Figure 7 below.

The asynchronous control reduces switching losses and improves the output (VHV) regulation of the DC/DC converter under light load, particularly in the situation where the TCC-206 only maintains the output voltages to fixed values.

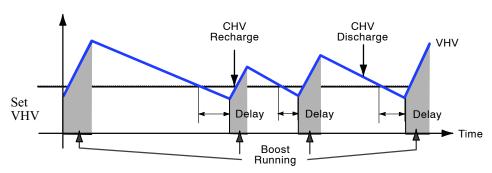


Figure 6. VHV Voltage Waveform

#### High Impedance (High Z) Feature

In shutdown mode the OUT pins are set to a high impedance mode (high Z). Following is the principle of operation for the control IC:

1. The DAC output voltage V<sub>OUT</sub> is defined by:

$$V_{OUT} = \frac{DAC \text{ code}}{255} \times 24 \text{ V} \times 2$$
 (eq. 1)

- 2. The voltage VHV defines the maximum supply voltage of the DAC supply output regulator and is set by a 4-bit control.
- 3. The maximum DAC DC output voltage  $V_{OUT}$  is limited to (VHV -2 V).
- The minimum output DAC voltage V<sub>OUT</sub> is 1.0 V max.

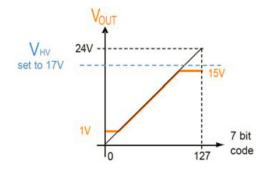


Figure 7. DAC Output Range Example A

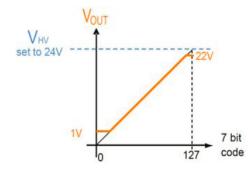


Figure 8. DAC Output Range Example B

#### **Digital Interface**

The control IC is fully controlled through a digital interface (DATA, CLK, CS). The digital interface automatically detects and responds to MIPI RFFE interface commands, 3-wire 30-bit serial interface commands or 3-wire 32-bit serial interface commands. Auto-detection is accomplished on a frame by frame basis. The digital interface is described in the following sections of this document, for detailed programming instructions please refer to the programming guide, available by contacting ON Semiconductor.

#### 3-Wire Serial Interface

The 3-wire serial interface operates in a synchronous write-only 3-wire slave mode. 30-bit or 32-bit message length is automatically detected for each frame. If CS changes state before all bits are received then all data bits are ignored. Data is transmitted most significant bit first and DATA is latched on the rising edge of CLK. Commands are latched on the falling edge of CS.

# Table 10. 3-WIRE SERIAL INTERFACE SPECIFICATION

(T<sub>A</sub> = -30 to +85°C; 2.3 V < AVDD < 5.5 V;  $V_{IO}$  = 1.8 V; unless otherwise specified)

Parameter	Description	Min	Тур	Max	Unit	Comments
F <sub>CLK</sub>	Clock Frequency	-	-	26	MHz	
T <sub>CLK</sub>	Clock Period	38.4	-	-	ns	
N <sub>BIT</sub>	Bits Number	-	30/32	-	bits	Auto-detection 30-bit or 32-bit
T <sub>HIGH</sub>	Clock High Time	13	-	-	ns	
$T_{LOW}$	Clock Low Time	13	-	-	ns	
TCS <sub>SETUP</sub>	CS Set-up Time	5	-	-	ns	70% rising edge of CS to 30% rising edge of first clock cycle
TCS <sub>HOLD</sub>	CS Hold Time	5	-	-	ns	30% falling edge of last clock cycle to 70% falling edge of CS
TD <sub>SETUP</sub>	Data Set-up Time	4	-	-	ns	Relative to 30% of CLK rising edge
TD <sub>HOLD</sub>	Data Hold Time	4	-	-	ns	relative to 70% of CLK rising edge
T <sub>SUCC</sub>	CS Low Time Between Successive Writes	38.4	_	-	ns	70% falling edge of CS to 70% rising edge of CS
T <sub>SUCC</sub>	CS Low Time Between Successive DAC Update Writes	1,500	-	-	ns	Time between groups of DAC update reg [00000] & [00001] writes
C <sub>CLK</sub>	Input Capacitance	-	-	5	pF	CLK pin
C <sub>DATA</sub>	Input Capacitance	-	-	8.3	рF	DATA pin
C <sub>CS</sub>	Input Capacitance	-	-	5	pF	CS pin
C <sub>TRIG</sub>	Input Capacitance	-	-	10	pF	TRIG pin
V <sub>IH</sub>	Input Logic Level High	0.7 x VIO	-	VIO x 0.3	V	DATA, CLK, CS
$V_{IL}$	Input Logic Level Low	-0.3	-	0.3 x VIO	V	DATA, CLK, CS
I <sub>IH_DATA</sub>	Input Current High	-2	-	10	μΑ	DATA
I <sub>IL_DATA</sub>	Input Current Low	-2	-	1	μΑ	DATA
I <sub>IH_CLK,CS</sub>	Input Current High	-1	-	10	μΑ	CLK, CS
I <sub>IL_CLK,CS</sub>	Input Current Low	-1	-	1	μΑ	CLK, CS
V <sub>TP_TRIG</sub>	Positive Going Threshold Voltage	0.4 x VIO	-	0.7 x VIO	V	TRIG
V <sub>TN_TRIG</sub>	Negative Going Threshold Voltage	0.3 x VIO	_	0.6 x VIO	٧	TRIG
V <sub>H_TRIG</sub>	Hysteresis Voltage (V <sub>TP</sub> – V <sub>TN</sub> )	0.1 x VIO	-	0.4 x VIO	V	TRIG
I <sub>IH_TRIG</sub>	TRIG Input Current High	-2	-	10	μΑ	TRIG=0.8 x VIO
I <sub>IL_TRIG</sub>	TRIG Input Current Low	-2	-	1	μΑ	TRIG=0.2 x VIO

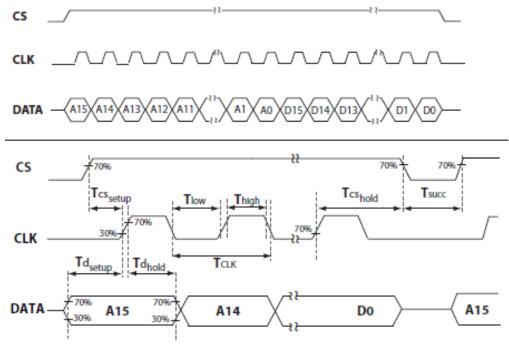


Figure 9. 3-wire Serial Interface Signal Timing

#### **SPI Frame Length Decoding**

30-bit or 32-bit frame length is automatically detected. The length of the frame is defined by the number of clock

rising edges while CS is kept high. The TCC-206 will not respond to a SPI command if the length of the frame is not exactly 30 bits or 32 bits. SPI registers are write only.

#### **SPI Frame Structure**

Table 11. 32 BITS FRAME: ADDRESS DECODING (1, 2, 3, 4, 5 or 6 OUTPUTS)

НО	H1	R/W	A12	A11	A10	A9	A8	<b>A</b> 7	A6	A5	A4	А3	A2	A1	Α0
1	1	0	1	0	1	0	0	1	0	0	Х	Х	Х	Х	Х
ON Semiconductor Header R/W		[	Device ID	)		Spec	ific Devi	ce ID		Reg	ister Ad	dress fo	r Opera	ition	

Table 12. 30 BITS FRAME: ADDRESS DECODING (1, 2, 3, 4, 5 or 6 OUTPUTS)

R/W	A12	A11	A10	A9	A8	A7	A6	A5	A4	А3	A2	A1	A0
0	1	0	1	0	0	1	0	0	Х	Х	Х	Х	X
R/W	I	Device ID			Specific Device ID				Register Address for Operation				

Table 13. 3-WIRE SERIAL INTERFACE ADDRESS MAP

A4	А3	A2	<b>A</b> 1	A0	Data[15:8]	Data[7:0]
0	0	0	0	0	Turbo-Charge Settings for DAC A, B, C	DAC C
0	0	0	0	1	DAC B	DAC A
0	0	0	1	0	Turbo-Charge Settings for DAC D, E, F	DAC F
0	0	0	1	1	DAC E	DAC D
0	0	1	0	0	Turbo-Charge Delay Parameters for DAC A, B, C	Turbo Threshold Delay Settings for A, B, C
0	0	1	0	1	Turbo-Charge Delay Parameters for DAC D, E, F	Turbo Threshold Delay Settings for A, B, C
1	0	0	0	0	Mode Select + Con	trol IC Setup
1	0	0	1	0	Reserved	Reserved
	to					
1	1	1	1	1		

#### Turbo-Charge Mode

The TCC–206 control IC has a Turbo–Charge mode that significantly shortens the system settling time when changing programming voltages. In Turbo–Charge mode the DAC output target voltage is temporarily set to either a delta voltage above or a delta voltage below the actual desired target for the TCDLY time. It is recommended that  $V_{\rm HV}$  be set to 26 V when using Turbo–Charge mode.

#### **Glide Mode**

Unlike turbo mode, which is intended to reduce the charging time, the glide mode extends the transition time of each DAC output. Each DAC has an individual control for turbo mode, glide mode or regular voltage switching. The glide mode can be enabled for a particular DAC through the INDEX register, by setting DAC State to '1' when glide mode is enabled, turbo mode is off for a particular DAC, but one DAC can be gliding while the other is turbo.

During glide mode the output voltage of a DAC is either increased or decreased to its set end point, in max 255 steps, where each DAC time step can be programmed between 2  $\mu$ s to 64  $\mu$ s. For programming the glide mode refer to the application note (coming soon). A programming input is not required to maintain a glide transition, all step controls are maintained by the part. Only the inputs to define the glide need to be programmed.

#### RF Front-End Control Interface (MIPI RFFE Interface)

The TCC-206 is a read/write slave device which is fully compliant to the MIPI Alliance Specification for RF Front-End Control Interface (RFFE) Version 1.10.00 26 July 2011. This device is rated at full-speed operation for 1.65 V<VIO<1.95 V and at half-speed operation for 1.1 V<VIO<1.65 V. When using the MIPI RFFE interface the CS pin must be grounded externally.

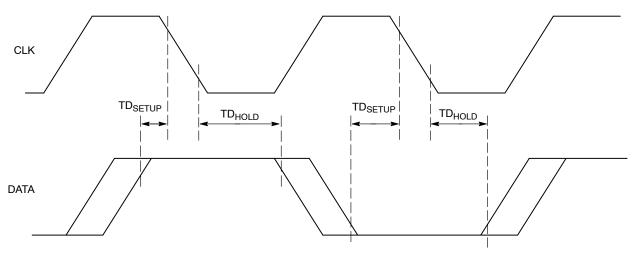


Figure 10. MIPI-RFFE Signal Timing during Master Writes to PTIC Control IC

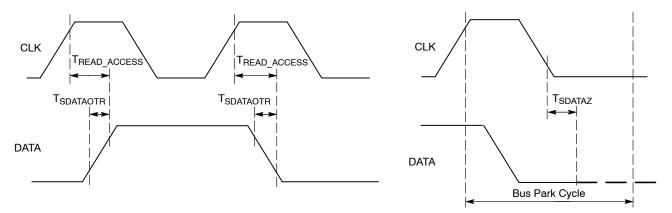


Figure 11. MIPI-RFFE Signal Timing during Master Reads from PTIC Control IC

Figure 12. Bus Park Cycle Timing when MIPI-RFFE Master Reads from PTIC Control IC

Table 14. MIPI RFFE INTERFACE SPECIFICATION (T<sub>A</sub> = -30 to +85°C; 2.3 V < AVDD < 5.5 V; 1.1 V < V<sub>IO</sub> < 1.8 V; unless otherwise specified)

Parameter	Description	Min	Тур	Max	Unit	Comments
F <sub>SCLK</sub>	Clock Full-Speed Frequency	0.032	-	26	MHz	Full-Speed Operation: 1.65 V < V <sub>IO</sub> < 1.95 V
T <sub>SCLK</sub>	Clock Full-Speed Period	0.038	-	32	μs	Full-Speed Operation: 1.65 V < V <sub>IO</sub> < 1.95 V
T <sub>SCLKIH</sub>	CLK Input High Time	11.25	-	-	ns	Full-Speed
T <sub>SCLKIL</sub>	CLK Input Low Time	11.25	-	-	ns	Full-Speed
$V_{TP}$	Positive Going Threshold Voltage	0.4 x VIO	-	0.7 x VIO	V	CLK, DATA, TRIG, 1.2 or 1.8 V Bus
$V_{TN}$	Negative Going Thresh- old Voltage	0.3 x VIO	-	0.6 x VIO	V	CLK, DATA, TRIG, 1.2 or 1.8 V Bus
V <sub>H</sub>	Hysteresis Voltage (V <sub>TP</sub> - V <sub>TN</sub> )	0.1 x VIO	-	0.4 x VIO	V	CLK, DATA, TRIG, 1.2 or 1.8 V Bus
I <sub>IH</sub>	Input Current High	-2	-	+10	μΑ	TRIG,SDATA = 0.8 x VIO
		-1	-	+10	μΑ	SCLK = 0.8 x VIO
I <sub>IL</sub>	Input Current Low	-2	-	+1	μΑ	TRIG,SDATA = 0.2 x VIO
		-1	-	+1	μΑ	SCLK = 0.2 x VIO
$C_{CLK}$	Input Capacitance	-	-	5	pF	CLK Pin
C <sub>DATA</sub>	Input Capacitance	-	-	8.3	pF	DATA Pin
C <sub>TRIG</sub>	Input Capacitance	-	-	10	pF	TRIG Pin
TD <sub>SETUP</sub>	Write DATA Setup Time	-	-	1	ns	Full-Speed
TD <sub>HOLD</sub>	Write DATA Hold Time	-	-	5	ns	Full-Speed
T <sub>READ_ACCESS</sub>	Read DATA valid from CLK rising edge	-	-	7.11	ns	Full Speed at $V_{IO}$ = 1.80 V, +25°C, and max 15 pF load on DATA pin
T <sub>READ_ACCESS</sub>	Read DATA valid from CLK rising edge	-	-	9.11	ns	Full Speed at $V_{IO}$ = 1.80 V, +25°C, and max 50 pF load on DATA pin

The control IC contains twenty–four 8-bit registers. Register content is described in Table 15. Some additional registers implemented as provision, are not described in this document.

Table 15. MIPI RFFE ADDRESS MAP

Register Address	Description	Purpose	Access Type	Size (bits
0x00	DAC Configuration (Enable Mask)	High voltage output enable mask	Write Reg0	7
0x01	Turbo Register DAC A, B & C	Turbo-charge configuration DAC A, B & C	Write	8
0x02	DAC A Register	OUT A value [6:0], Turbo Index [7]**	Write	8
0x03	DAC B Register	OUT B value [6:0], Turbo Index [7]**	Write	8
0x04	DAC C Register	OUT C value [6:0], Turbo Index [7]**	Write	8
0x05	Turbo Register DAC D, E & F	Turbo-charge configuration DAC D,E & F	Write	8
0x06	DAC D Register	OUT D value [6:0], Turbo Index [7]**	Write	8
0x07	DAC E Register	OUT E value [6:0], Turbo Index [7]**	Write	8
0x08	DAC F Register	OUT F value [6:0], Turbo Index [7]**	Write	8
0x09	Wake Up	Wake Up Controls	Write	8
0x10	DAC Boost (VHV)	Settings for the boost high voltage	Write	8
0x11	Trigger register	Trigger configuration	Write	8
0x12	Turbo-Charge Delay DAC A, B, C	Turbo-charge delay steps DAC A, B, C	Write	8
0x13	Turbo-Charge Delay DAC A, B, C	Turbo-charge delay, multiplication DAC A, B, C	Write	8
0X14	Turbo-Charge Delay DAC D, E, F	Turbo-charge delay steps DAC D, E, F	Write	8
0X15	Turbo-Charge Delay DAC D, E, F	Turbo-charge delay multiplication DAC D, E, F	Write	8
0x1A	RFFE_STATUS	RFFE status register	Read/Write	8
0x1B	RFFE_GROUP_SID		Read/Write	8
0x1C	Power Mode and Trigger Register	Power mode & trigger control PWR_MODE [7:6] TRIG_REG [5:0]	Read/Write	8
0x1D	Product ID Register	Product number * Hard coded into ASIC	Read	8
0x1E	Manufacturer ID Register	MN (10 bits long) Manufacturer ID[7:0] Hard Coded into ASIC	Read	8
0x1F	Unique Slave Identifier Register (USID)	Spare [7:6] [5,4] = Manufacturer ID [9:8] USID [3:0]	Read/Write	8
0x2C	Glide Timer Settings	[6:5] Turbo and glide control / [4:0] Glide timer setting / Need extended write for this register	Write	8

<sup>\*</sup>The second least significant bit can be programmed in OTP during manufacture

#### **Configuration Settings**

Table 16. DAC CONFIGURATION (ENABLE MASK) at [0x00] Defaults shown as (x)

I	Bit 6 (1)	Bit 5 (0)	Bit 4 (0)	Bit 3 (0)	Bit 2 (0)	Bit 1 (0)	Bit 0 (0)
	SSE	DAC E	DAC F	DAC A	DAC B	DAC C	DAC D

SSE = 0 spread spectrum disabled, SSE = 1 spread spectrum enabled (default), this controls the average boost clock which is nominally 2 MHz and spread between 0.8 MHz and 3.2 MHz when enabled (default). The hardware does not limit driving more than three DACs at the same time, however it is recommended to have max three DACs changing outputs at one time, no restrictions exist as to which three.

<sup>\*\*</sup> The details for configuration of Turbo mode should be ascertained from the Programming Guide, available from ON Semiconductor

Table 17. DAC MODE SETUP: DAC ENABLE

Bit3	Bit2	Bit1	DAC A	DAC B	DAC C	
0	0	0	Off	Off	Off	(Default)
0	0	1	Off	Off	Enabled	
0	1	0	Off	Enabled	Off	
0	1	1	Off	Enabled	Enabled	
1	0	0	Enabled	Off	Off	
1	0	1	Enabled	Off	Enabled	
1	1	0	Enabled	Enabled	Off	
1	1	1	Enabled	Enabled	Enabled	

### Table 18. DAC MODE SETUP: DAC ENABLE

Bit5	Bit4	Bit0	DAC E	DAC F	DAC D	
0	0	0	Off	Off	Off	(Default)
0	0	1	Off	Off	Enabled	
0	1	0	Off	Enabled	Off	
0	1	1	Off	Enabled	Enabled	
1	0	0	Enabled	Off	Off	
1	0	1	Enabled	Off	Enabled	
1	1	0	Enabled	Enabled	Off	
1	1	1	Enabled	Enabled	Enabled	

### Table 19. BOOST DAC MODE SETUP (VHV) at [0x10] (Notes 4 and 5)

Bit 7*	Bit 6*	Bit 5*	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	VHV (V)
0	0	0	1	0	0	0	0	13
0	0	0	1	0	0	0	1	14
0	0	0	1	0	0	1	0	15
0	0	0	1	0	0	1	1	16
0	0	0	1	0	1	0	0	17
0	0	0	1	0	1	0	1	18
0	0	0	1	0	1	1	0	19
0	0	0	1	0	1	1	1	20
0	0	0	1	1	0	0	0	21
0	0	0	1	1	0	0	1	22
0	0	0	1	1	0	1	0	23
0	0	0	1	1	0	1	1	24 (Default)
0	0	0	1	1	1	0	0	25
0	0	0	1	1	1	0	1	26
0	0	0	1	1	1	1	0	27
0	0	0	1	1	1	1	1	28

<sup>\*</sup>Indicates reserved bits

<sup>4.</sup> Bit 4 is fixed at logic 1 for reverse software compatibility
5. VHV is recommended to be set at VDac Max + 2 V for non-turbo operation and +4 when turbo is used.\* Indicates reserved bits.

#### **MIPI RFFE TRIG Operation**

The MIPI RFFE Trigger mode can be used as a synchronization signal to ensure that new DAC settings are applied to the outputs at appropriate times in the overall transceiver system. When the MIPI RFFE TRIG function is enabled via [0x11] bit 4 the requested DAC voltage levels are set up in the shadow registers and not transferred to the destination registers until the trigger condition is met. In this manner the change in output voltage levels are synchronized with the MIPI RFFE TRIG command. If multiple DAC voltage level requests are received before the TRIG event occurs, only the last fully received DAC output voltage level will be applied to the outputs.

The trigger configuration also provides for an additional external TRIG pin to be used as a synchronization signal. The external TRIG is independent from the built-in triggers available within the MIPI RFFE interface. When the TRIG input pin is enabled via [0x11] bit 4 the requested DAC voltage levels are set up in the shadow registers and are not transferred to the destination registers until the external trigger condition is met. In this manner the change in output voltage levels are synchronized with the external TRIG event. The external TRIG input is referenced to VIO. To

improve interfacing options the polarity of external TRIG is programmable via [0x11] bit 1.

If the external trigger function is not needed in the application, the TRIG pin should be grounded and the TRIG function disabled. When TRIG pin is disabled by register [0x11] 'TRIG Select' = '1' (default) and register [0x10] 'Trigger Mask 0, 1, 2' = '1':

- The requested DAC voltage levels for DAC A, B, C are applied to the outputs all together at the same time, after DAC C value is written. This event will not affect the outputs of DAC D, E, F.
- The requested DAC voltage levels for DAC D, E, F are applied to the outputs all together at the same time, after DAC F value is written. This event will not affect the outputs of DAC A, B, C.
- Optionally a configuration register can select the last DAC to be written in order to trigger internally the update of all six DACs at the same time. For example the configuration register can select that a write to DAC B value will trigger internally the update of all six DACs outputs.

Table 20. TRIGGER CONFIGURATION at [0x11]

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Res* 0	Res* 0	Res* 0	TRIG Select 0 = Ext TRIG Pin 1 = RFFE Trigger	Rese (	erved )	TRIG Edge 0 = Active Falling 1 = Active Rising	Mask Ext TRIG 1 = Mask Trig Pin

<sup>\*</sup>Reserved bits

Table 21. EXTERNAL TRIGGER CONFIGURATION BIT SETTING AT [0x11]

Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Description
0	-	-	Х	0	External trigger pin is enabled. Sending the RFFE message will load a 'shadow' register only. Only upon an active signal on external TRIG pin are the output registers loaded with the new voltage settings which are then applied to the outputs.
1	-	_	Х	Х	The MIPI RFFE trigger is enabled (Default)
0	-	-	0	0	External TRIG pin signal is active falling
0	-	-	1	0	External TRIG pin signal is active rising (Default)
Х	_	_	Х	0	External trigger pin is not masked
Х	_	-	Х	1	Mask external trigger pin (Default)

Table 22. POWER MODE AND TRIGGER REGISTER [0x1C]

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
PM1	PM0	Trigger Mask 2	Trigger Mask 1	Trigger Mask 0	Trigger 2	Trigger 1	Trigger 0

Writing a logic one ('1') to the bits 0, 1 or 2 (Trigger 0, 1 or 2) moves data from the shadow registers into the destination registers. Default for bit 0, 1 and 2 is logic low.

If trigger mask bit 0, 1 or 2 is set ('1') the trigger 0, 1 or 2 are disabled respectively and the data goes directly to the destination register. Default for bit 3, 4 and 5 is logic low.

All three triggers behave in the same way as the external pin TRIG. When each of these triggers is set using the MIPI RFFE interface the results are the same as when an active edge is applied to the TRIG pin when external pin TRIG is selected

Table 23. POWER MODE BIT SETTING IN REGISTER [0x1C]

PM1	PM0	State	Description
0	0	Active	Boost Control Active, VHV set by Digital Interface V <sub>OUT</sub> A, B, C, D, E, F Enabled and Controlled by Digital Interface (Default)
0	1	Startup	Boost Control Active, VHV set by Digital Interface V <sub>OUT</sub> A, B, C, D, E, F Disabled
1	0	Low Power	Digital Interface is Active While All Other Circuits are in Low Power Mode
1	1	Reserved	State of Hardware Does Not Change

#### **Command Sequences**

- Register 0 Write (used to access the Register 0 DAC Configuration Enable Mask). Register 0 can be also be accessed using Register Write or/and Extended Register Write.
- **Register Write** (used to access only one register at the time)
- Extended Register Write (used to access a group of contiguous registers with one command)

#### **Register 0 Write Command Sequence**

The Command Sequence starts with a Sequence Start Condition (SSC) which is followed by the Register 0 Write Command Frame. This Frame contains the Slave address, a logic one, and the seven bit word that will be written to Register 0. The Command Sequence is depicted below.

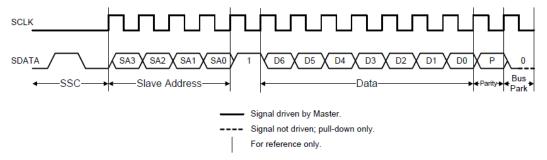


Figure 13. Register 0 Write Command Sequence

#### Table 24. MIPI RFFE COMMAND FRAME FOR REGISTER 0 WRITE COMMAND SEQUENCE

Description	S	SC					Comma	nd Frame					BP
SSE & DAC Configuration	1	0	SA [3,0]	1	SSE	DAC_E	DAC_F	DAC_A	DAC_B	DAC_C	DAC_D	Р	BP

# **Register Write Command Sequence**

The write register command sequence may be used to access each register (addresses 0–31).

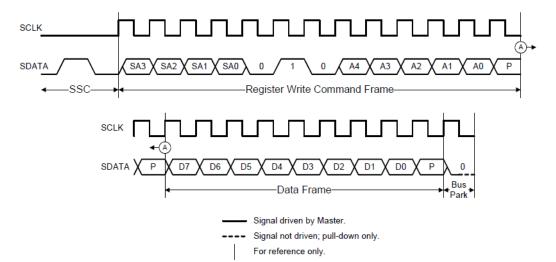


Figure 14. Register Write Command Sequence

#### Table 25. MIPI RFFE COMMAND FRAME FOR REGISTER WRITE COMMAND SENTENCE

Description	S	sc				Com	mand	Fram	ne				Data Frame		BP
Turbo-Charge Settings	1	0	SA [3,0]	0	1	0	0	0	0	0	1	Р	TC_INDX_L [7:0]	Р	BP
Register Write DAC A	1	0	SA [3,0]	0	1	0	0	0	0	1	0	Р	TC_INDX_L [8] & DAC_A [6:0]	Р	BP
Register Write DAC B	1	0	SA [3,0]	0	1	0	0	0	0	1	1	Р	TC_INDX_L [9] & DAC_B [6:0]	Р	BP
Register Write DAC C	1	0	SA [3,0]	0	1	0	0	0	1	0	0	Р	TC_INDX_L [10] & DAC_C [6:0]	Р	BP

#### Table 26. MIPI RFFE COMMAND FRAME FOR REGISTER WRITE COMMAND SENTENCE

Description	S	sc				Com	mand	Fran	ne .				Data Frame		ВР
Turbo-Charge Settings	1	0	SA [3,0]	0	1	0	0	0	1	0	1	Р	TC_INDX_U [7:0]	Р	BP
Register Write DAC D	1	0	SA [3,0]	0	1	0	0	0	1	1	0	Р	TC_INDX_U [8] & DAC_D [6:0]	Р	BP
Register Write DAC E	1	0	SA [3,0]	0	1	0	0	0	1	1	1	Р	TC_INDX_U [9] & DAC_E [6:0]	Р	BP
Register Write DAC F	1	0	SA [3,0]	0	1	0	0	1	0	0	0	Р	TC_INDX_U [10] & DAC_F [6:0]	Р	BP

#### **Extended Register Write Command Sequence**

In order to access more than one register in one sequence this message could be used. Most commonly it will be used for loading three DAC registers at the same time. The four LSBs of the extended register write command frame determine the number of bytes that will be written by the command sequence. A value of 0b0000 would write one byte and a value of 0b1111 would write 16 bytes.

If more than one byte is to be written, the register address in the command sequence contains the address of the first extended register that will be written to and the slave's local extended register address shall be automatically incremented by one for each byte written up to address 0x1F, starting from the address indicated in the address frame.

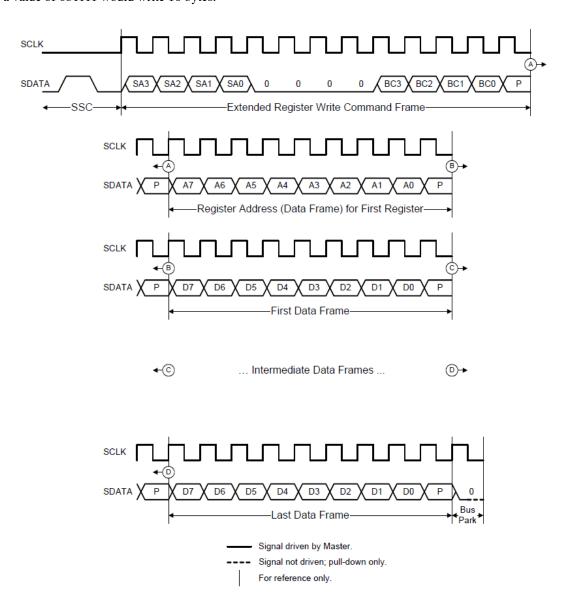


Figure 15. Extended Register Write Command Sequence

### Table 27. EXTENDED REGISTER WRITE TO UPDATE DAC A, B, C (Note 6)

Description	SS	SC			(	Com	mar	nd F	rame								Addr	ess F	rame	)		
Extended Register Write TC_INDX_L					·	ОрО	Code	)	<e< td=""><td>Byte (</td><td>Count</td><td>×.</td><td>Р</td><td></td><td></td><td><sta< td=""><td>rting</td><td>Addre</td><td>ess&gt;</td><td></td><td></td><td>Р</td></sta<></td></e<>	Byte (	Count	×.	Р			<sta< td=""><td>rting</td><td>Addre</td><td>ess&gt;</td><td></td><td></td><td>Р</td></sta<>	rting	Addre	ess>			Р
and DAC A, B, C	1	0	SA	[3,0]	0	0	0	0	0	0	1	1	Р	0	0	0	0	0	0	0	1	Р

Data Frame		Data Frame		Data Frame		Data Frame		ВР
<data 8-bit=""></data>	Р	BP						
Turbo-Charge	Р	DAC_A [7,0]	Р	DAC_B [7,0]	Р	DAC_C [7,0]	Р	BP

#### Table 28. EXTENDED REGISTER WRITE TO UPDATE DAC D, E, F (Note 6)

Description	SS	С				Con	nma	nd F	rame	е							Addr	ess F	rame	)		
Extended Register Write TC_INDX_U						Ор (	Code		<b>&lt;</b> l	Byte (	Coun	t>	Р			<sta< td=""><td>ırting</td><td>Addre</td><td>ess&gt;</td><td></td><td></td><td>Р</td></sta<>	ırting	Addre	ess>			Р
and DAC D, E, F	1	0	SA	[3,0]	0	0	0	0	0	0	1	1	Р	0	0	0	0	0	1	0	1	Р

Data Frame		Data Frame		Data Frame		Data Frame		BP
<data 8-bit=""></data>	Р	BP						
Turbo-Charge	Р	DAC_D [7,0]	Р	DAC_E [7,0]	Р	DAC_F [7,0]	Р	BP

<sup>6.</sup> The six DACs can be updated either all together in the same time by using one Extended Register Write command of 8 bytes, or separately by using two Extended Register Write commands of 4 bytes each, where one command is to update DAC A, B, C and the other command to update DAC D, E, F.

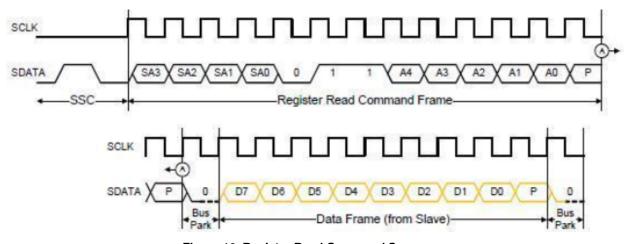


Figure 16. Register Read Command Sequence

#### **Table 29. REGISTER READ COMMAND**

Description	SS	SC .					Comma	nd Fram	е				
Read MIPI-RFFE Status Register	1	0	SA[3:0]	0	1	1	1	1	0	1	0	Р	BP

Description					Data Fram	ne			
Read MIPI-RFFE Status Register (Continued)	0	CFPE	CLE	AFPE	DFPE	RURE	WURE	BGE	BP

#### **REGISTER DETAILS**

Register RFFE:	RFFE_REG_0x00	Address RFFE A[4:0]:	0x00

Reset Source: nreset dig or SWR = '1' or PWR MODE = '01' (transition through STARTUP mode)

	6	5	4	3	2	1	0
Bits	SS Enable	DAC E	DAC F	DAC A (1)	DAC B (1)	DAC C (1)	DAC D
Reset	W-1	W-0	W-0	W-0	W-0	W-0	W-0

- (1) When any of the bits [3:1] are written with '0', the corresponding DAC is disabled, but the Turbo-Charge process which is already started, will not be stopped.
- (2) If all bits [3:1] are '0', then incoming DAC messages will be ignored, until at least one of [3:1] is set '1'. Bit 6: Spread Spectrum enable

0: SS disabled

1: SS enabled

Bit [1]: Control DAC E

0: off (default)

1: enabled

Bit [1]: Control DAC F

0: off (default)

1: enabled

Bit [3]: Control DAC A

0: off (default)

1: enabled

Bit [2]: Control DAC B

0: off (default)

1: enabled

Bit [1]: Control DAC C

0: off (default)

1: enabled

Bit [1]: Control DAC D

0: off (default)

1: enabled

Register RFF	E: RFFE_	REG_0x01			Ad	ddress RFFE A[4:0	]: 0x01	
Reset Source	: nreset_dig o	r SWR = '1'	or PWR_MO	DE = '01' (t	ransition t	hrough START	JP mode)	
	7	6	5	4	3	2	1	0
Bits				TC_IN	DX_L[7:0]			
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0
Register RFFE Reset Source		REG_0x02 or SWR = '1'	or PWR_MC	DDE = '01' (		ddress RFFE A[4:0] through STARI	•	
		_	or PWR_MC	DDE = '01' (			•	0
		or SWR = '1'			transition	through START	•	0

Register RFFE	: RFFE_R	EG_0x03			Addre	ess RFFE A[4:0]	]: 0x03		
Reset Source:	nreset_dig or	SWR = '1' o	or PWR_MO	DE = '01' (1	ransition thr	ough STARTU	JP mode)		
	7	6	5	4	3	2	1	0	
Bits	TC_INDX_L [9]			•	DAC B value	[6:0]	•		
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0	
Register RFFE	: RFFE_R	EG_0x04			Addre	ess RFFE A[4:0]	]: 0x04		
Reset Source:	nreset_dig or	SWR = '1'	or PWR_MO	DE = '01' (1	ransition thr	ough STARTU	JP mode)		
	7	6	5	4	3	2	1	0	
Į.	ı								
Bits	TC_INDX_L [10]				DAC C value	[6:0]			
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0	
Register RFFE	: RFFE_R	EG_0x05			Addre	ess RFFE A[4:0]	]: 0x05		
1) Reset Sou	rce: nreset_dig	or SWR = '	1' or PWR_	MODE = '0	l' (transition	through STA	RTUP mode	)	
	7	6	5	4	3	2	1	0	
Bits	_		TC_INDX_U[7:0]						
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0	
Register RFFE Reset Source:	: RFFE_R	EG_0x06 SWR = '1' o	or PWR_MO	DDE = '01' (1		ess RFFE A[4:0 rough START			
	7	6	5	4	3	2	1	0	
Bits	TC_INDX_U [8]				DAC D value	[6:0]	<u>,                                    </u>		
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0	
•							•		
Register RFFE	:: RFFE_R	EG_0x07			Addre	ess RFFE A[4:0	)]: 0x07		
Reset Source	: nreset_dig or	SWR = '1' c	or PWR_MO	DE = '01' (tı	ansition thro	ough STARTU	P mode)		
	7	6	5	4	3	2	1	0	
Bits	TC_INDX_U [9]				DAC E value	e [6:0]			
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0	
Register RFFE	:: RFFE_R	EG_0x08			Addr	ess RFFE A[4:0	]: 0x08		
Reset Source	: nreset_dig or	SWR = '1' c	or PWR_MO	DE = '01' (tı	ansition thro	ough STARTU	P mode)		
	7	6	5	4	3	2	1	0	
	TC_INDX_U				DAC F value [6:0]				
Bits	[10]								

Register RFFE: RFFE_REG_0x9 Address RFFE A[4:0]: 0x09
---

Reset Source: nreset\_dig or SWR = '1' or PWR\_MODE = '01' (transition through STARTUP mode)

	7	6	5	4 3		2	1	0
Bits	HW Wake-Up Polarity		HW Wake- Up Disable			Turbo Latency Select	Reserved	boost_en_fast_st (OTP duplicated) (2)
Reset	W-0	W-1	W-0	W-0	W-0	W-0	W-0	W-0

- 1. Changing RFFE\_REG\_0x09 bits [7:5] while chip is in LP STD mode does not have effect, until chip returns to ACTIVE mode because bits [7:5] are shadowed when entering LP STD mode.
- 2. boost en fast st can be set in ACTIVE or in LP mode
  - Bit [7:6]: HW Wake-Up Polarity
    - 00: HW Wake-Up is always active LOW
    - 01: (default) HW Wake-Up is always active HIGH
    - 10: HW Wake-Up has inverted polarity referred to TRIG pin:
      - a. when RFFE REG 0x11/TRIG SEL = 1, HW Wake-Up is always active LOW
      - b. when RFFE REG 0x11/TRIG SEL = 0, HW Wake-Up is:
        - i. active LOW if RFFE\_REG\_0x11/TRIG\_EDGE = 0 ii. active HIGH if RFFE\_REG\_0x11/TRIG\_EDGE = 1
    - 11: HW Wake-Up has same polarity as TRIG pin:
      - a. when RFFE\_REG\_0x11/TRIG\_SEL = 1, HW Wake-Up is always active HIGH
      - b. when RFFE REG 0x11/TRIG SEL = 0, HW Wake-Up is:
        - i. active HIGH if RFFE\_REG\_0x11/TRIG\_EDGE = 0
        - ii. active LOW if RFFE REG 0x11/TRIG EDGE = 1
    - Bit [5]: HW Wake-Up Disable
      - 0: (default) HW Wake-Up is enabled
      - 1: HW Wake-up is disabled
    - Bit [4:3]: DAC Wake-up Control applicable to Wake-up from LP
      - 00: (default) Don't apply Turbo when Wake-up from LP
      - 01: Always apply Turbo UP when Wake-up from LP. Turbo UP is calculated based on DAC value prior to enter
      - LP STD mode.
      - 10: Apply Turbo UP when Wake-up from LP when HW Wake-up is applied, but don't apply Turbo UP when
      - SW Wake-up is applied
      - 11: unused
  - NOTE 1: Turbo is NOT appl i ed after Wake-up to the DACs which are programmed with 0x00 in the DAC value register
  - NOTE 2: When Bi t[4:3] = '10' or '01', then Turbo i s appl i ed after Wake-up regardl ess if:
- DAC values are updated or not
- l ast DAC val ue update i s equal with old DAC val ue
  - NOTE 3: When RFFE\_REG\_0x31 / Wake-up DAC Ctrl i s '0' (default) Turbo after Wake-Up i s appl i ed after fi rst vhv\_too\_low fal ling edge is detected. When RFFE\_REG\_0x31 / Wake-up DAC Ctrl i s '1' Turbo after Wake-up i s appl i ed after rc clk starts.
    - Bit [2]: Turbo UP latency Select when Wake-up from LP.
    - This field has no effect when DAC WAKEUP CTRL[1:0] = '00'
      - 0: (default) Turbo UP latency is 50us
      - 1: Turbo UP latency is 100us
    - Bit [1]: Fast Transition to Active Mode Enable
      - 0: (default) Slow, current as low as possible in LP mode
      - 1 Fast, RC oscillator and bandgap stay on, refer to section 5.6.2.4.2
    - Bit [0]: Boost Fast Startup Enable
      - 0: (default) Startup with selected boost\_il\_trim
    - 1: Startup with boost\_il\_trim\_st[2:0], only if OTP[59]=1. The value of boost\_il\_trim\_st[2:0] is applied starting from the moment when RFFE\_REG\_0x1C / Power Mode filed is written '00' during LP mode, until first vhv\_too\_low negative edge is detected.

Register RFFE	: RFFE	FFE_REG_0x10				ress RFFE A[4:0	]: 0x10	0x10	
Reset Source: nreset_dig or SWR = '1' or PWR_MODE = '01' (transition through STARTUP mode)									
	7	6	5	4	3	2	1	0	
Bits		Reserved			Boost voltage value				
Reset	U-0	U-0	U-0	U-1	W-1	W-1			

Bit [3:0]: Boost voltage value Refer to Table 19 for values

The MIPI RFFE Trigger Modes can be used as a synchronization signal to ensure that new DAC settings are applied to the outputs at appropriate times in the overall transceiver system. When the RFFE TRIG function is enabled via the TRIG SEL bit of RFFE\_REG\_0x11the requested DAC voltage levels are set up in the shadow registers and not transferred to the destination registers until the trigger condition is met. In this manner the change in output voltage levels are synchronized with the RFFE TRIG command. The trigger configuration also provides for an external TRIG pin to be used as a synchronization signal. When the TRIG input pin is enabled via the TRIG SEL bit of RFFE\_REG\_0x11the requested DAC voltage levels are set up in the shadow registers and are not transferred to the destination registers until the external trigger condition is met. In this manner the change in output voltage levels are synchronized with the external TRIG event. The external TRIG input is referenced to VIO. To improve interfacing options the polarity of external TRIG is programmable via TRIG\_edge bit of RFFE REG\_0x11. When MIPI RFFE trigger and the external TRIG input are disabled by

MASK\_EXT\_TRIG of RFFE\_REG\_0x11 and TRIGGER\_MASK[5:3] of RFFE\_REG\_0x1C, the requested DAC voltage levels are immediately applied to the outputs and are not synchronized with the RFFE Trigger Modes or the external TRIG signal.

When valid trigger edge occurs, only the completely received messages are subject to be applied to the outputs.

A message is considered to be completed, if the TRIG edge occurs after TRIG\_LAT following last SDL clock falling edge in the frame.

In Figure 17, the last SDL clock cycle in each frame is highlighted gray.

The parameter TRIG\_LAT is represented as the latency following the SDL last falling edge in the frame until TRIG edge occurs.

As an example, in Figure 17 TRIG edge 3 occurs before TRIG\_LAT, following last SDL falling edge in frame of "MESSAGE A3", so TRIG edge 3 will move "MESSAGE A2" to output, instead of "MESSAGE A3". In this case TRIG edge 3 has the same effect as TRIG edge 2, which is described below.

If trigger edge occurs while a message frame is being received by the slave on the serial bus, than the pending message will not be transferred to the output until next trigger edge occurs after frame transfer is completed.

A pending message is considered from the moment SSC cycle starts, until after TRIG\_LAT following last SDL falling edge in the frame.

For example, in Figure 17, both TRIG edge 2 and TRIG edge 3 occur while "MESSAGE A3" is pending. In this case both will have same effect, which is to transfer "MESSAGE A2" to the output.

"MESSAGE A3" will be transferred to the output by TRIG edge 4, because it occurs after TRIG LAT.

If more than one message was received before a trigger edge, than only the last completed message will be transferred to the output.

For example, in Figure 17, between TRIG edge 1 and TRIG edge 2, there have been two messages sent: "MESSAGE A1" and "MESSAGE A2". In this case, "MESSAGE A1" will be ignored, and only "MESSAGE A2" will be transferred to the output by TRIG edge 2.

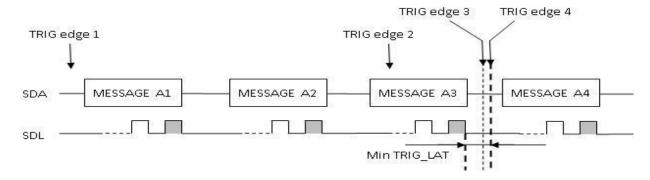


Figure 17. Sequences of Triggers and Messages to Same Output

In Figure 18, TRIG edge 2, will transfer "MESSAGE A2", "MESSAGE B1", and "MESSAGE C1" to the respective outputs, but will ignore "MESSAGE A1".

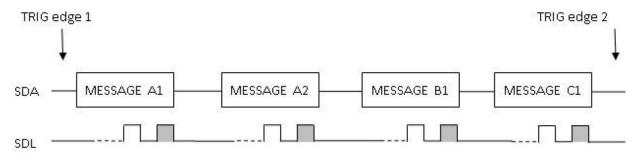


Figure 18. Sequences of Triggers and Messages to Different Outputs

#### Table 30. TRIG LAT PARAMETER TIMING

Symbol	Description	Min	Max	Unit
	Latency following the falling edge of last clock cycle of a certain message, until the moment a TRIG edge is allowed to update the value sent by that message	5	25	ns

Register RFFE	: RFFE	RFFE_REG_0x11				Address RFFE A[4:0]: 0x11				
	7	6	5	4	3		2	1		0
Bits	Reserved		TRIG SEL	Reserved		TRIG E (1) (2	-	MASK EXT TRIG		
Reset	U-0	U-0	U-0	W-1	U-(	)	U-0	W-	1	W-1

- (1) Following sequence is required when changing the expected polarity of TRIG pin:
  - a) TRIG\_SEL = '1' (disable TRIG pin)
  - b) TRIG EDGE = new value
  - c) TRIG SEL = '0' (enable TRIG pin)
- (2) After power–up, first configure TRIG\_Edge, then write TRIG\_SEL = '0' Bit 4: TRIG Select 0: Use external TRIG pin. Sending the RFFE message will load a 'shadow' registers only. Only upon an active signal on external TRIG pin are the output registers loaded with the new voltage settings which are then applied to the outputs. Software triggers generated by bits [2:0] of RFFE\_REG\_0x1C are ignored when external TRIG pin is selected.
  - 1: External TRIG pin will not be used. (default)
- Bit [1]: TRIG edge
  - 0: TRIG pin active falling
  - 1: TRIG pin active rising (default)
- Bit [0]: MASK EXT TRIG
  - 0: External trigger is not masked
  - 1: Mask external trigger pin (default)

Turbo mode timing is controlled by these registers:

Register RFFE:	RFFE_REG_0x12	Address RFFE A[4:0]:	0x12
Reset Source: prese	t dig or SWR = '1' or PWR	MODE - '01' (transition through STARTLIP mod	de)

Reset Source: nreset\_dig or SWR = '1' or PWR\_MODE = '01' (transition through STARTUP mode)

	7	6	5	4	3	2	1	0
Bits	Reserved		TC_STP_DAC_C		TC_STP_DAC_B		TC_STP_DAC_A	
Reset	U-0	U-0	W-0	W-1	W-0	W-1	W-0	W-1

Register RFFE:	RFFE_REG_0x13	Address RFFE A[4:0]:	0x13

Reset Source: nreset\_dig\_or SWR = '1' or PWR\_MODE = '01' (transition through STARTUP mode)

	7	6	5	4	3	2	1	0	
Bits	Rese	erved	TCM_C		TCN	И_В	TCM_A		
Reset	U-0	U-0	W-0	W-0	W-0 W-0		W-0	W-0	

Register RFFE	E: RFFE	RFFE_REG_0x14				Address RFFE A[4:0]:			0x14	
Reset Source: nreset_dig or SWR = '1' or PWR_MODE = '01' (transition through STARTUP mode)										
	7	6	5	4	3		2	1		0
Bits	Rese	Reserved		TC_STP_DAC_F		TC_STP_DAC_E		TC_STP_DAC_D		P_DAC_D
Reset	U-0	U-0	W-0	W-1	W-0		W-1	W-0	)	W-1

Register RFFE	: RFFE	RFFE_REG_0x15				Address RFFE A[4:0]:			0x15	
Reset Source: nreset_dig or SWR = '1' or PWR_MODE = '01' (transition through STARTUP mode)										
	7	6	5	4	3	2	1		0	
Bits	Reserved		TCM_F		TCM_E		TCM_D		CM_D	
Reset	U-0	U-0	W-0	W-0	W-0	W-0	W-0	)	W-0	

Register RFFE	E: RFFE	_STATUS_0x1A	4		А	Address RFFE A[4	:0]: 0x	IA
Reset Source: nreset_dig or SWR = '1' or PWR_MODE = '01' (transition through STARTUP mode)								
	7	6	5	4	3	2	1	0
Bits	SWR	CFPE	CLE	AFPE	DFPE	RURE	WURE	BGE
Reset	W-0	R-0	R-0	R-0	R-0	R-0	R-0	R-0

TC_STP_DAC_x[1:0]	Turbo steps for TCDLY [us]
00	3
01 (default)	5
10	7
11	9

TCM_x[1:0]	Turbo Multiplication Factor
00 (default)	4
01	3
10	2
11	1

Step (μs)	DAC state	0	1	2	3	4	5	6	7	8	9	10	11
9	TCDLY	Turbo	OFF	18	27	36	45	54	63	72	81	90	99
7	TCDLY	Turbo	OFF	14	21	28	35	42	49	56	63	70	77
5 (default)	TCDLY	Turbo	OFF	10	15	20	25	30	35	40	45	50	55
3	TCDLY	Turbo	OFF	6	9	12	15	18	21	24	27	30	33

The value of Turbo time is deducted based on the hardware comparison of new DAC value in respect to old DAC value, as follows:

If DAC new > DAC old, then TUP = TCDLY

If DAC new < DAC old, and DAC new\_divby2 < 21, then TDOWN = TCDLY + TCM \* (21 – DAC\_new\_divby2) If DAC new < DAC old, and DAC new divby2 > 21, then TDOWN = TCDLY

If DAC new < DAC old, and DAC new divby2 = 21, then TDOWN = TCDLY

RFFE\_STATUS register can be read any time after power-up without the need to enable the Read Operation as described in section 6.9.5

SWR Soft-Reset MIPI-RFFE registers

Write '1' to this bit to reset all the MIPI-RFFE registers, except RFFE\_REG\_0x1C, RFFE\_USID, and

#### RFFE GROUP SID

This bit will always Read-back '0'.

The soft reset occurs in the last clock cycle of the MIPI-RFFE frame which Writes '1' to this bit. Right immediately after this frame, all the MIPI-RFFE registers have the reset value and are ready to be reprogrammed as desired.

The OTP duplicated registers are reset to the values written in OTP.

SWR can be written only by USID messages. GSID and Broadcast frames will be ignored when writing to this register field.

RFFE\_STATUS Bits [6:0] are set '1' by hardware to flag when a certain condition is detected, as described below. RFFE\_STATUS Bits [6:0] cannot be written, but it is cleared to '0' under following conditions:

- Hardware Self-reset is applied after RFFE\_STATUS is READ
- When SWR is written '1' with USID frames
- When power mode transitions through STARTUP mode '01'
- After Power–up Reset

#### **CFPE**

1: Command frame with parity error received.

On the occurrence of this error, the slave will ignore the entire Command Sequence

#### **CLE**

1: Incompatible command length, due to unexpected SSC received before command length to be completed.

On the occurrence of this error, the slave will accept Write data up to the last correct and complete frame. When MIPI-RFFE multi-byte Read command is detected, the slave will always replay with an extended Read command of length of one byte.

#### **AFPE**

1: Address frame with parity error received.

On the occurrence of this error, the slave will ignore the entire Command Sequence

#### DFPF

1: Data frame with parity error received.

#### **RURE**

On the occurrence of this error, the slave will ignore only the erroneous data byte (s)

1: Read of non-existent register was detected.

On the occurrence of this error, the slave will not respond to the Read command frame.

When the Read Operation is not enabled according to section 6.9.5, any read from an address other than

0x1A, will set RURE and the slave will not respond to the Read command frame.

When the Read Operation is enabled according to section 6.9.5, any read from an unoccupied RFFE register address will set RURE.

#### **WURE**

1: Write to non-existent register was detected.

On the occurrence of this error, the slave discards data being written, and on the next received frame, proceeds as normal

#### **BGE**

1: Read using the Broadcast ID was detected

On the occurrence of this error, the slave will ignore the entire Command Sequence

Register RFFE:	RFFE_GROUP_SID_0x1B	Address RFFE A[4:0]:	0x1B
----------------	---------------------	----------------------	------

Reset Source: nreset dig or PWR MODE = '01' (transition through STARTUP mode)

	7	6	5	4	3	2	1	0
Bits	Reserved	Reserved	Reserved	Reserved	GSID[3]	GSID[2]	GSID[1]	GSID[0]
Reset	0	0	0	0	W-0	W-0	W-0	W-0

GSID = Group Slave Identifier Register

NOTE: The GSID[3:0] field can be written directly by messages using USID. NOTE: GSID value is NOT retained during

SHUTDOWN power mode. NOTE: GSID value is not affected by SWR bit from RFFE STATUS register

NOTE: Frames using USID = GSID, can write only to RFFE REG 0x1C [7:6] and [2:0].

NOTE: RFFE READ frames containing GSID will be ignored

Register RFFE:	RFFE_REG_0x1C	Address RFFE A[4:0]:	0x1C					
Reset Source: preset dig or PWR_MODE = '01' (transition through STARTUP_mode)								

set Source: nreset\_dig or PWR\_MODE = '01' (transition through STARTUP mode)

	7	7 6 5		4	3	2	1	0
Bits	Power Mode (5)		wer Mode (5)		Trigger Mask 0 (1) (2) (3) (4)	Trigger 2	Trigger 1	Trigger 0
Reset	W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0

- (1) Trigger Mask bits [5:3] can be changed, either set or cleared, only with an individual message
- (2) During broadcast MIPI-RFFE accesses using GSID = '0000', Trigger bits [2:0] are masked by the pre-existent setting of Trigger Mask Bits [5:3]
- (3) During Individual MIPI-RFFE accesses using USID, Trigger bits [2:0] are masked by the incoming Trigger Mask bits [5:3] within the same write message to RFFE REG 0x1C register. During Individual MIPI-RFFE accesses using USID, pre-existent setting of Trigger Mask Bits [5:3] is ignored.
- (4) When RFFE REG 0x11 / TRIG SEL = '1' (External TRIG pin will not be used) and RFFE REG 0x1C/Trigger Mask 2 = '1' and Trigger Mask 1 = '1' and Trigger Mask 0 = '1', then DAC messages will be sent to DACs immediately after RFFE REG 0x04 is received, without waiting for any trigger
- (5) Power mode field bits [7:6] and Triggers bits [2:0] can be changed by either MIPI-RFFE broadcast messages when USID field within the Register Write Command is 0x0, or individual messages when USID fields within the Register Write Command is equal with RFFE REG 0x1F[3:0] NOTE: All the 8 bits of RFFE REG 0x1C register bits are NOT affected by SWR bit from RFFE STATUS register

Bit [7:6]: Power Mode

- 00: ACTIVE mode, defined by following hardware behavior:
- Boost Control active, VHV set by Digital Interface
- Vout A, B, C enabled and controlled by Digital Interface
- 01: STARTUP mode, defined by following hardware behavior:
- Boost Control active, VHV set by Digital Interface
- Vout A, B, C disabled
- 10: LOW POWER mode when TRIG pin = LOW, ACTIVE mode when TRIG pin = HIGH. LOW POWER mode is defined by following hardware behavior:
- Digital interface is active, while all other circuits are in low power mode
- 11: Reserved (State of hardware does not change)

Bit 5: Mask trigger 2

0:Trigger 2 not masked. Data goes to destination register after bit 2 is written value 1 (default)

1:Trigger 2 is masked. Data goes directly to the destination register

Bit 4: Mask trigger 1

0:Trigger 1 not masked. Data goes to destination register after bit 1 is written value 1(default)

1:Trigger 1 is masked. Data goes directly to the destination register.

Bit 3: Mask trigger 0

0:Trigger 0 not masked. Data goes to destination register after bit 0 is written value 1(default)

1:Trigger 0 is masked. Data goes directly to the destination register.

Bit 2: Trigger 2

Write 1 to this bit, to move data from shadow registers into destination register. This trigger can be masked by bit 5.

Bit 1: Trigger 1

Write 1 to this bit, to move data from shadow registers into destination register. This trigger can be masked by bit 4.

Bit 0: Trigger 0

Write 1 to this bit, to move data from shadow registers into destination register. This trigger can be masked by bit 3.

All three triggers from register [0x1C] behave in the same way as the external pin TRIG. When each of these triggers is set using the MIPI RFFE interface the results are the same as when an active voltage level is applied to the TRIG pin when External pin TRIG is selected.

Register RFFE	E:	RFFE_PRODUCT_ID_0x1D						Address RFFE A[4:0]:			0x1D	
Reset Source: N/A												
	7		6	5	4	3		2	1		0	
Bits	PID:	7	PID6	PID5	PID4	PID	3	PID2	PID	1	PID0 (1)	
Reset	0		0	1	0	0		1	OTP	[4]	IDB0 pin	

Bits [7:2] are hardcoded in ASIC

Bits [1:0] can be programmed in OTP during manufacturing

The MIPI register RFFE PRODUCT ID can be read in SPI mode as described in 6.9.5

Register RFFE	: RFI	Addre	Address RFFE A[4:0]: 0x1E							
Reset Source:	: N/A									
	7	6	5	4	3		2	1		0
Bits	MPN7	MPN6	MPN5	MPN4	MPN	13	MPN2	MPN	<b>J</b> 1	MPN0
Reset	0	0	1	0	1		1	1		0
		•	-							
Register RFFE	:: RFI	FE_USID_0x1F				Addre	ess RFFE A[4:0	)]:	0x1F	
Reset Source:	Reset Source: nreset_dig or PWR_MODE = '01' (transition through STARTUP mode)									
	7	6	5	4	3		2	1		0
Bits	Res	served (2)	MPN9 (2)	MPN8 (2)	USID3	3 (1)	USID2 (1)	USID1	(1)	USID0 (1)

USID = Unique Slave Identifier Register

Reset

- (1) USID field can be changed by:
- MIPI-RFFE broadcast messages when USID field within the Register Write Command is 0b0000

W-0

W-1

W-1

W-1

- MIPI-RFFE individual messages when USID field within the Register Write Command equal with content of RFFE\_REG\_0x1F[3:0]
- (2) In the sequence of writing USID field, the upper [7:4] must match the value 0b0001 hard-coded in the RFFE register 0x1F

NOTE: USID value is NOT retained during SHUTDOWN power mode.

NOTE: USID value is not affected by SWR bit from RFFE STATUS register DAC Update

Following picture shows TCC-206 and all the necessary external components

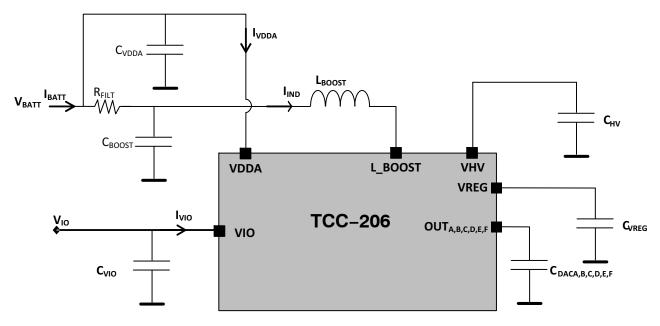


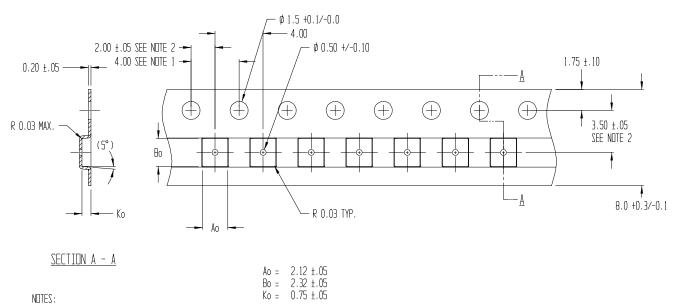
Figure 19. TCC-206 with External Components

**Table 31. RECOMMENDED EXTERNAL BOM** 

Component	Description	Nominal Value	Package	Recommended P/N
C <sub>BOOST</sub>	Boost Supply Capacitor, 10 V	1 μF	0402	TDK: C1005X5R1A105K
L <sub>BOOST</sub>	Boost Inductor	15 μΗ	0603	TDK: VLS2010ET-150M, Sunlord SPH201610H150MT
R <sub>FILT</sub>	Filtering resistor, 5%	3.3 Ωs	0402	Vishay : CRCW04023R30JNED
C <sub>VIO</sub>	V <sub>IO</sub> Supply Decoupling, 10 V	100 nF	0201	Murata: GRM033R61A104ME15D
C <sub>AVDD</sub>	V <sub>AVDD</sub> Supply Decoupling, 10 V	1 μF	0402	TDK: C1005X5R1A105K
C <sub>VREG</sub>	V <sub>VREG</sub> Supply Decoupling, 10 V	220 nF	0201	TDK: C0603X5R1A224M
C <sub>HV</sub>	Boost Tank Capacitor, 50 V	47 nF	1005	Murata: GRM155C71H473KE19
C <sub>dacA,B,C,D,E,F</sub>	Decoupling Capacitor, 50 V (Note 7)	100 pF	0201	Murata: GRM0335C1H101JD01D

<sup>7.</sup> Recommended for noise reduction only – not essential

#### **TAPE & REEL DIMENSIONS**



- 1. 10 SPROCKET HOLE PITCH CLMULATIVE TOLERANCE ±0.2
- 2. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE
- Ao and Bo are calculated on a plane at a distance "R" above the bottom of the pocket.

Figure 20. WLCSP Carrier Tape Drawings

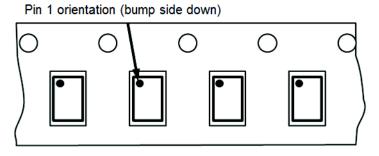


Figure 21. Orientation in Tape

**Table 32. ORDERING INFORMATION** 

Device	Package	Shipping <sup>†</sup>
TCC-206A-RT	RDL (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **ASSEMBLY INSTRUCTIONS**

Note: It is recommended that under normal circumstances, this device and associated components should be located in a shielded enclosure.



#### WLCSP20 2.187x1.987 CASE 567JV **ISSUE B**

**DATE 27 JAN 2015** 

#### NOTES:

- NOTES.

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. COPLANARITY APPLIES TO SPHERICAL

CROV	WNS OF SOLDER BALLS					
	IETERS					
DIM	MIN	MAY				

	IVIII LIIVIL I LIIO			
DIM	MIN	MAX		
Α		0.65		
A1	0.17	0.23		
A2	0.38 REF			
b	0.23	0.29		
D	2.187 BSC			
E	1.987 BSC			
е	0.40 BSC			

#### **GENERIC MARKING DIAGRAM\***



= Assembly Location

L = Wafer Lot

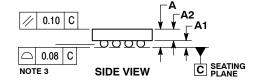
Υ = Year

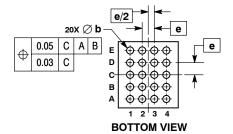
W = Work Week

= Pb-Free Package

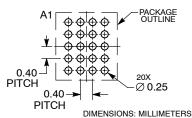
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

# Ε Α В PIN A1 REFERENCE D 2X \alpha 0.05 \cdot C 0.05 C **TOP VIEW**





#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON84825F	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	WLCSP20 2.187X1.987		PAGE 1 OF 1

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

#### **PUBLICATION ORDERING INFORMATION**

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi

TCC-206A-RT